# NSN 5961-00-958-8041

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Inclosure Material:

Metal

**Overall Length:** 

0.114 inches

# **Overall Diameter:**

0.830 inches

# Mounting Facility Quantity:

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0 breakdown

voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 7.50 amperes source cutoff current and 15.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Terminal Type And Quantity:

2 pin

#### **Specification Data:**

80131-release4716 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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